

#### **Features**

- 2.5 A maximum peak output current
- 2.0 A minimum peak output current
- 250 ns maximum propagation delay over temperature range
- 1.7A Active Miller Clamp. Clamp pin short to V<sub>EE</sub> if not in used
- Miller Clamping
- Desaturation Detection
- Under Voltage Lock-Out Protection (UVLO) with Hysteresis
- Open Collector Isolated fault feedback
- "Soft" IGBT Turn-off
- 100 ns maximum pulse width distortion (PWD)
- 50 kV/µs minimum common mode rejection (CMR) at V<sub>CM</sub> = 1500 V
- I<sub>CC</sub>(max) <4.5 mA maximum supply current
- Wide V<sub>CC</sub> operating range: 15 V to 30 V over temperature range
- Wide operating temperature range: –40-110°C

# **Applications**

- Isolated IGBT/Power MOSFET gate drive
- AC and brushless DC motor drives
- Industrial inverters and Uninterruptible Power Supply(UPS)

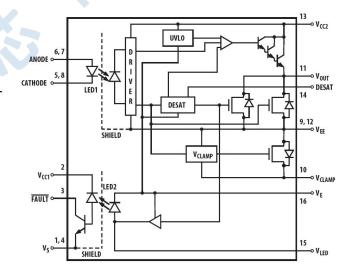
# **Description**

The ICPL-332J contains a AlGaAs LED. The LED is optically coupled to an integrated circuit with a power output stage. ICPL-332J is ideally suited for driving power IGBTs and MOSFETs used in motor control inverter applications. The voltage and current supplied by these optocouplers make them ideally suited for directly driving IGBTs with ratings up to 1200 V and 150 A. For IGBTs with higher ratings, the ICPL-332J can be used to drive a discrete power stage which drives the IGBT gate.

The ICPL-332J has an insulation voltage of VIORM = 1414VPEA

#### Caution

It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.









### ORDERING INFORMATION

Outline	Part Number	Package	Marking	Packing	Packing Size	Quantity		
			ICPL					
THE PARTY OF THE P	ICPL-332J-500E	SOP16	332J	Reel	13 "	1000		
But the state of t			/YYWW					

ICPL-332J

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# PIN CONFIGURATION AND FUNCTIONS

		PIN CONFIGURATION AND FUNCTIONS				
		1 V <sub>s</sub> V <sub>E</sub> 16				
		2 V <sub>CC1</sub> V <sub>LED</sub> 15				
		3 FAULT DESAT 14				
		4 V <sub>s</sub> V <sub>cc2</sub> 13				
		5 CATHODE V <sub>EE</sub> 12				
		6 ANODE V <sub>out</sub> 11				
		7 ANODE V <sub>CLAMP</sub> 10				
		8 CATHODE V <sub>EE</sub> 9				
Pin	Symbol	Description				
1	Vs	Input Ground				
2	$V_{CC1}$	Positive input supply voltage. (3.3 V to 5.5 V)				
		Fault output. FAULT changes from a high impedance state to a logic low output within 5 µs of the voltage on the DESAT pin exceeding an internal reference voltage of 6.5 V.				
3	FAULT	FAULT output is an open collector which allows the FAULT outputs from all ICPL-332J in a circuit to be connected together in a "wired OR" forming a single fault bus for inter-facing directly to the micro-controller.				
4	Vs	Input Ground				
5	CATHODE	Cathode				
6	ANODE	Anode				
7	ANODE	Anode				
8	CATHODE	Cathode				
9	V <sub>EE</sub>	Output supply voltage.				
10	$V_{CLAMP}$	Miller clamp				
11	V <sub>OUT</sub>	Gate drive voltage output				
12	V <sub>EE</sub>	Output supply voltage.				
13	V <sub>CC2</sub>	Positive output supply voltage				
14	DESAT	Desaturation voltage input. When the voltage on DESAT exceeds an internal reference voltage of 6.5 V while the IGBT is on, FAULT output is changed from a high impedance state to a logic low state within 5 μs.				
15	$V_{LED}$	LED anode. This pin must be left unconnected for guaran- teed data sheet performance. (For optical coupling testing only)				
16	V <sub>E</sub>	Common (IGBT emitter) output supply voltage.				

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# **ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Min.	Max.	Units	Note
Storage Temperature	Tstg	-55	125	℃	
Operating Temperature	T <sub>A</sub>	-40	110	$^{\circ}$	2
Output IC Junction Temperature	TJ		125	C	2
Average Forward Input Current	IF		20	mA	1
Peak Transient Input Current			1.0		
(<1 µs pulse width, 300pps)	I <sub>F</sub> (TRAN)		1.0	А	
Reverse Input Voltage	VR		5	V	
"High" Peak Output Current	I <sub>OH(PEAK)</sub>		2.5	Α	3
"Low" Peak Output Current	I <sub>OL(PEAK)</sub>		2.5	Α	3
Positive Input Supply Voltage	V <sub>CC1</sub>	-0.5	7.0	V	
FAULT Output Current	I <sub>FAULT</sub>		8.0	mA	
FAULT Pin Voltage	V <sub>FAULT</sub>	-0.5	V <sub>CC1</sub>	V	
Total Output Supply Volta	(V <sub>CC2</sub> - V <sub>EE</sub> )	-0.5	33	V	
Negative Output Supply Voltage	(V <sub>E</sub> - V <sub>EE</sub> )	-0.5	15	V	6
Positive Output Supply Voltage	(V <sub>CC2</sub> - V <sub>E</sub> )	-0.5	33-(V <sub>E</sub> -V <sub>EE</sub> )	V	
Gate Drive Output Voltage	V <sub>O(PEAK)</sub>	-0.5	V <sub>CC2</sub>	V	
Peak Clamping Sinking Current	I <sub>Clamp</sub>		1.7	Α	
Miller Clamping Pin Voltage	$V_{Clamp}$	-0.5	V <sub>CC2</sub>	V	
DESAT Voltage	V <sub>DESAT</sub>	VE	V <sub>E</sub> +10	V	
Output IC Power Dissipation	Po		600	mW	2
Input IC Power Dissipation	Pı		150	mW	2



# **RECOMMENDED OPERATION CONDITIONS**

Parameter	Symbol	Min	Max	Units	Note
Operating Temperature	T <sub>A</sub>	-40	110	°C	2
Total Output Supply Voltage	(V <sub>CC2</sub> - V <sub>EE</sub> )	15	30	V	7
Negative Output Supply Voltage	(V <sub>E</sub> - V <sub>EE</sub> )	0	15	V	4
Positive Output Supply Voltage	(V <sub>CC2</sub> - V <sub>E</sub> )	15	30-(V <sub>E</sub> -V <sub>EE</sub> )	V	
Input Current (ON)	I <sub>F(ON)</sub>	8	12	mA	
Input Voltage (OFF)	$V_{F(OFF)}$	-3.6	0.8	V	





# **ELECTRICAL OPTICAL CHARACTERISTICS**

Unless otherwise noted, all typical values at  $T_a = 25$ °C,  $V_{CC2} - V_{EE} = 30$ V,  $V_E - V_{EE} = 0$ V; All Minimum/Maximum specifications are at Recommended Operating Conditions.

Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions	Note
FAULT Logic Low	V <sub>FAULTL</sub>	-	0.01	0.4	V	I <sub>FAULT</sub> = 1.1 mA, V <sub>CC1</sub> = 5.5V	
Output Voltage	VIAULIL	-	0.02	0.4	V	I <sub>FAULT</sub> = 1.1 mA, V <sub>CC1</sub> = 3.3V	
FAULT Logic High	I <sub>FAULTH</sub>	-	0.01	0.5	μA	V <sub>FAULT</sub> = 5.5 V, V <sub>CC1</sub> = 5.5V	
Output Current		-	0.006	0.3	μA	$V_{\text{FAULT}} = 3.3 \text{ V}, V_{\text{CC1}} = 3.3 \text{ V}$	
High Level	Іон	-	-2	-0.5	Α	$V_0 = V_{CC2} - 4$	5
Output Current		-	-	-2.0	A	$V_0 = V_{CC2} - 15$	3
Low Level	I <sub>OL</sub>	0.5	2	-	Α	$V_0 = V_{EE} + 2.5$	5
Output Current		2.0	-	-	А	Vo = V <sub>EE</sub> + 15	3
Low Level Output Current During Fault Condition	I <sub>OLF</sub>	70	100	230	mA	V <sub>OUT</sub> - V <sub>EE</sub> = 14 V	6
High Level Output Voltage	V <sub>OH</sub>	V <sub>CC</sub> -0.5	V <sub>cc</sub> -0.1	-	V	Ι <sub>ο</sub> = -650 μΑ	7,8,9,23
Low Level Output Voltage	Vol	-	0.1	0.5	V	I <sub>O</sub> = 100 mA	
Clamp Pin Threshold Voltage	V <sub>tClamp</sub>	-	2.2	-	٧		
Clamp Low Level Sinking Current	I <sub>CL</sub>	0.35	1.0		Α	V <sub>O</sub> = V <sub>EE</sub> + 2.5	
High Level Supply Current	I <sub>CC2H</sub>	-	2.23	5	mA	I <sub>O</sub> = 0 mA	9
Low Level Supply Current	I <sub>CC2L</sub>	-	2.36	5	mA	I <sub>O</sub> = 0 mA	
Blanking Capacitor Charging Current	I <sub>CHG</sub>	0.13	-0.24	-0.33	mA	V <sub>DESAT</sub> = 2 V	9,10
Blanking Capacitor Discharge Current	I <sub>DSCHG</sub>	10	31	-	mA	V <sub>DESAT</sub> = 7.0 V	
DESAT Threshold	V <sub>DESAT</sub>	6	6.7	7.5	V	V <sub>CC2</sub> -V <sub>E</sub> >V <sub>UVLO-</sub>	9
UVLO Threshold	$V_{\text{UVLO+}}$	10.5	11.5	12.5	V	V <sub>0</sub> > 5 V	7,9,11
OVEO TITESTIOI	V <sub>UVLO-</sub>	9.2	10.5	11.1	V	V <sub>0</sub> < 5 V	7,9,12
UVLO Hysteresis	(V <sub>UVLO+</sub> - V <sub>UVLO-</sub> )	0.4	1	-	V		
Threshold Input Current Low to High	I <sub>FLH</sub>	-	0.27	5	mA	I <sub>O</sub> = 0 mA, V <sub>O</sub> > 5 V	
Threshold Input Voltage High to Low	$V_{FHL}$	0.8	1.74	-	V		
Input Forward Voltage	V <sub>F</sub>	1.6	2.0	2.4	V	I <sub>F</sub> = 10 mA	
Input Reverse Breakdown Voltage	BV <sub>R</sub>	5	-	-	V	I <sub>R</sub> = 10 μA	
Input Capacitance	C <sub>IN</sub>	-	70	-	pF	f = 1 MHz, V <sub>F</sub> = 0 V	

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### **SWITCHING SPECIFICATION**

Unless otherwise noted, all typical values at  $T_a$  = 25°C,  $V_{CC2}$  -  $V_{EE}$  = 30V,  $V_E$  -  $V_{EE}$  = 0V; All Minimum/Maximum specifications are at Recommended Operating Conditions.

Millimum/Maximum specifications are at Recommended Operating Conditions.							
Parameter	Symbol	Min	Тур	Max	Units	Test Conditions	Note
Propagation Delay Time to Output Low Level	t <sub>PHL</sub>	50	94	250	ns		
Propagation Delay Time to Output High Level	t <sub>PLH</sub>	50	97	250	ns	A	13,15
Pulse Width Distortion	PWD	-100	-	100	ns	Rg = 10 Ω, Cg = 10 nF, f = 10 kHz, Duty Cycle = 50%,	14,17
Propagation Delay Difference Between Any Two Parts	PDD (t <sub>PHL</sub> - t <sub>PLH</sub> )	-150	-	150	ns	I <sub>F</sub> = 10 mA, V <sub>CC2</sub> = 30 V	17,16
Rise Time	t <sub>r</sub>	-	22		ns	.1.	
Fall Time	t <sub>f</sub>	-	14	-	ns		
DESAT Sense to 90% VO Delay	t <sub>DESAT(90%)</sub>	-	0.1	0.5	μs	$C_{DESAT}$ = 100pF, $R_F$ =2.1k $\Omega$ , $Rg$ = 10 $\Omega$ , $Cg$ = 10 nF, $V_{CC2}$ = 30 V	19
DESAT Sense to 10% VO Delay	t <sub>DESAT(10%)</sub>	-	2.3	3	μs	$C_{DESAT}$ = 100pF, $R_F$ =2.1k $\Omega$ , $Rg$ = 10 $\Omega$ , $Cg$ = 10 nF, $V_{CC2}$ = 30 $V$	
DESAT Sense to Low Level		-	0.2	0.5	μs	$C_{DESAT}$ = 100 pF, $R_F$ = 2.1 $k\Omega$ , $C_F$ = Open, $Rg$ = 10 $\Omega$ , $Cg$ = 10 nF, $V_{CC2}$ = 30 $V$	
FAULT Signal Delay	t <sub>DESAT(FAULT)</sub>	3	0.8	-	μs	$C_{DESAT}$ = 100 pF, $R_F$ = 2.1k $\Omega$ , $C_F$ = 1 nF, $Rg$ = 10 $\Omega$ , $Cg$ = 10 nF, $V_{CC2}$ = 30 V	18
DESAT Sense to DESAT Low Propagation Delay	tdesat(low)	-	0.15	-	μs	$C_{DESAT} = 100 pF, R_F = 2.1 k\Omega,$ $Rg = 10 \Omega, Cg = 10 nF,$ $V_{CC2} = 30 V$	19
DESAT Input Mute	t <sub>DESAT(MUTE)</sub>	5	-	-	μs	$C_{DESAT} = 100 pF, R_F = 2.1 k\Omega,$ $Rg = 10 \Omega, Cg = 10 nF,$ $V_{CC1} = 5.5 V, V_{CC2} = 30 V$	20
RESET to High Level FAULT Signal Delay	treset(Fault)	0.2	0.6	2.0	μs	$C_{DESAT}$ = 100pF, RF = 2.1 k $\Omega$ ,Rg = 10 $\Omega$ , Cg = 10 nF,V <sub>CC1</sub> = 5.5V, V <sub>CC2</sub> = 30 V	
RESET to High Level FAULT Signal Delay	t <sub>RESET(FAULT)</sub>	0.2	0.6	2.5	μs	$C_{DESAT}$ = 100pF, RF = 2.1 k $\Omega$ ,Rg = 10 $\Omega$ , Cg = 10 nF,V <sub>CC1</sub> = 3.3V, V <sub>CC2</sub> = 30 V	
Output High Level Common Mode Transient Immunity	CM <sub>H</sub>	15	-	-	kV/µs	$T_A = 25^{\circ}C$ , $I_F = 10 \text{ mA V}_{CM} = 1500 \text{ V}$ , $V_{CC2} = 30 \text{ V}$ , $R_F = 2.1 \text{ k}\Omega$ , $C_F = 15 \text{ pF}$	21
Wode Hansierit IIIIIIunity		50	-	-		$T_A = 25$ °C, $I_F = 1$ mA $V_{CM} = 1500$ V, $V_{CC2} = 30$ V, $R_F = 2.1$ k $\Omega$ , $C_F = 1$ nF	21,2 6
Output Low Level Common	CM <sub>L</sub>	15	-	-	kV/μs	$T_A = 25$ °C, $V_F = 0 VV_{CM} = 1500 V$ ,	22

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Mode Transient Immunity				$V_{CC2} = 30V,RF = 2.1k\Omega, C_F = 15pF$
	50	_	_	$T_A = 25^{\circ}C$ , $V_F = 0 \ VV_{CM} = 1500 \ V$ ,
				$VCC2 = 30V,R_F = 2.1k\Omega, C_F = 1nF$

#### Notes:

- 1. Derate linearly above 70°C free air temperature at a rate of 0.3 mA/°C.
- 2. In order to achieve the absolute maximum power dissipation specified, pins 4, 9, and 10 require ground plane connections and may require airflow. See the Thermal Model section in the application notes at the end of this data sheet for details on how to estimate junction temperature and power dissipation. In most cases the absolute maximum output IC junction temperature is the limiting factor. The actual power dissipation achievable will depend on the application environment (PCB Layout, air flow, part placement, etc.). See the Recommended PCB Layout section in the application notes for layout considerations. Output IC power dissipation is derated linearly at 10 mW/°C above 90°C. Input IC power dissipation does not require derating.
- 3. Maximum pulse width = 10  $\mu$ s. This value is intended to allow for component tolerances for designs with I<sub>O</sub> peak minimum = 1.0 A. Derate linearly from 2.0 A at +25°C to 1.5 A at +105°C. This compensates for increased I<sub>OPEAK</sub> due to changes in V<sub>OL</sub> over temperature.
- 4. This supply is optional. Required only when negative gate drive is implemented.
- 5. Maximum pulse width =  $50 \mu s$ .
- 6. See the Slow IGBT Gate Discharge During Fault Condition section in the applications notes at the end of this data sheet for further details.
- 7. 15 V is the recommended minimum operating positive supply voltage ( $V_{CC2}$   $V_E$ ) to ensure adequate margin in excess of the maximum  $V_{UVLO+}$  threshold of 12.5 V. For High Level Output Voltage testing,  $V_{OH}$  is measured with a dc load current. When driving capacitive loads,  $V_{OH}$  will approach  $V_{CC}$  as  $I_{OH}$  approaches zero units.
- 8. Maximum pulse width = 1.0 ms.
- 9. Once  $V_O$  of the ICPL-332J is allowed to go high ( $V_{CC2} V_E > V_{UVLO+}$ ), the DESAT detection feature of the ICPL-332J will be the primary source of IGBT protection. UVLO is needed to ensure  $D_{ESAT}$  is functional. Once  $V_{CC2}$  is increased from 0V to above  $V_{UVLO+}$ , DESAT will remain functional until  $V_{CC2}$  is decreased below  $V_{UVLO-}$ . Thus, the DESAT detection and UVLO features of the ICPL-332J work in conjunction to ensure constant IGBT protection.
- 10. See the DESAT fault detection blanking time section in the applications notes at the end of this data sheet for further details.
- 11. This is the "increasing" (i.e. turn-on or "positive going" direction) of  $V_{CC2}$   $V_E$
- 12. This is the "decreasing" (i.e. turn-off or "negative going" direction) of  $V_{\text{CC2}}$   $V_{\text{E}}$
- 13. This load condition approximates the gate load of a 1200 V/75A IGBT.
- 14. Pulse Width Distortion (PWD) is defined as |tphl tplh| for any given unit.
- 15. As measured from IF to  $V_{\text{O}}$ .
- 16. The difference between t<sub>PHL</sub> and t<sub>PLH</sub> between any two ICPL-332J parts under the same test conditions.
- 17. As measured from ANODE, CATHODE of LED to V<sub>OUT</sub>

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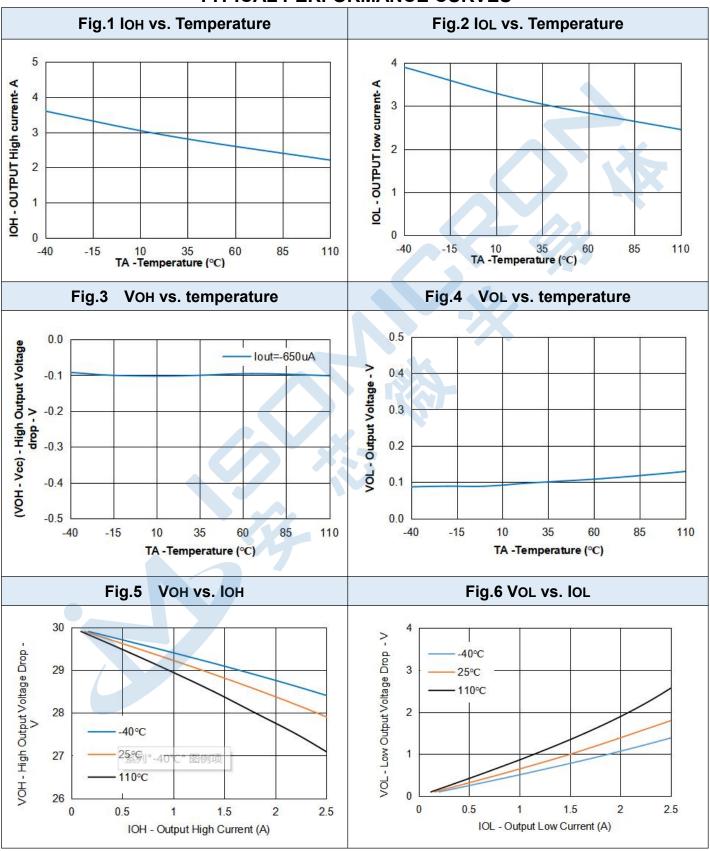


- 18. This is the amount of time from when the DESAT threshold is exceeded, until the FAULT output goes low.
- 19. This is the amount of time the DESAT threshold must be exceeded before V<sub>OUT</sub> begins to go low, and the FAULT output to go low. This is supply voltage dependent.
- 20. Auto Reset: This is the amount of time when V<sub>OUT</sub> will be asserted low after DESAT threshold is exceeded. See the Description of Operation (Auto Reset) topic in the application information section.
- 21. Common mode transient immunity in the high state is the maximum tolerable  $dV_{CM}/dt$  of the common mode pulse,  $V_{CM}$ , to assure that the output will remain in the high state (i.e.,  $V_O > 15 \text{ V}$  or FAULT > 2 V).
- 22. Common mode transient immunity in the low state is the maximum tolerable  $dV_{CM}/dt$  of the common mode pulse,  $V_{CM}$ , to assure that the output will remain in a low state (i.e.,  $V_O < 1.0 \text{ V}$  or FAULT < 0.8 V).
- 23. To clamp the output voltage at  $V_{CC}$  3  $_{VBE}$ , a pull-down resistor between the output and  $V_{EE}$  is recommended to sink a static current of 650  $\mu$ A while the output is high. See the Output Pull-Down Resistor section in the application notes at the end of this data sheet if an output pull-down resistor is not used.
- 24. In accordance with UL 1577, each optocoupler is proof tested by applying an insulation test voltage ≥ 6000 Vrms for 1 second. This test is performed before the 100% production test for partial discharge (method b) shown in IEC/EN/DIN EN 60747-5-5 Insulation Characteristic Table.
- 25. This is a two-terminal measurement: pins 1-8 are shorted together and pins 9-16 are shorted together.
- 26. Split resistors network with a ratio of 1:1 is needed at input LED1.





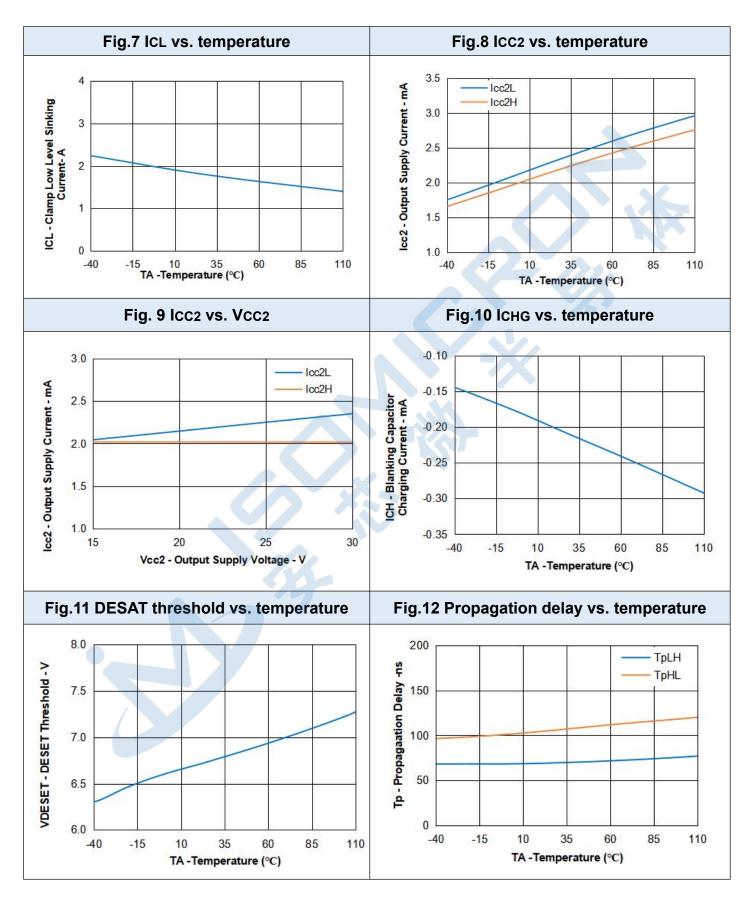
### TYPICAL PERFORMANCE CURVES



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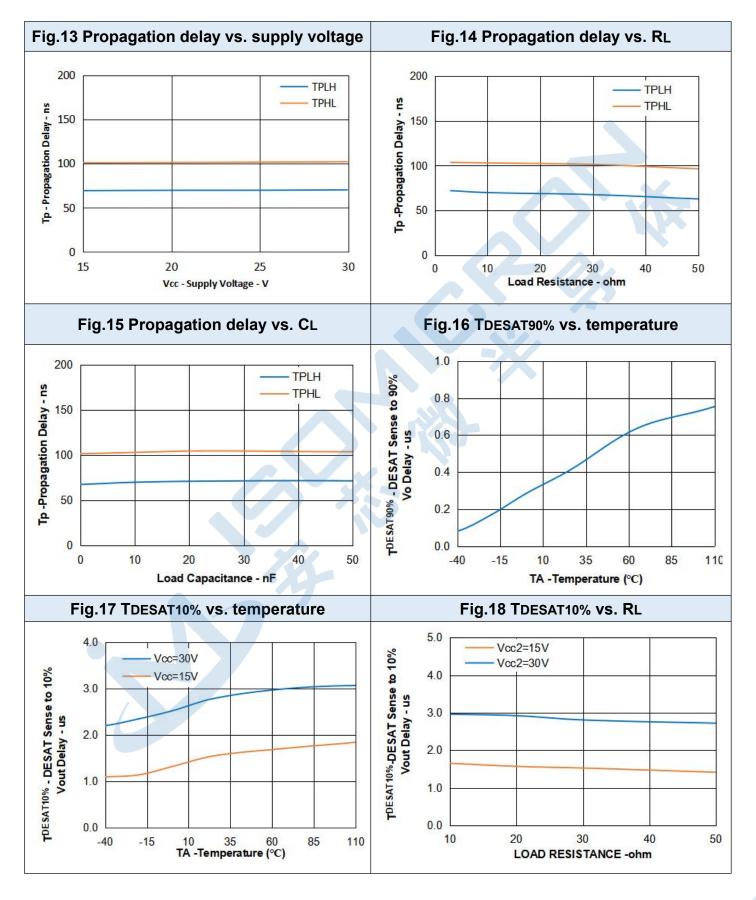




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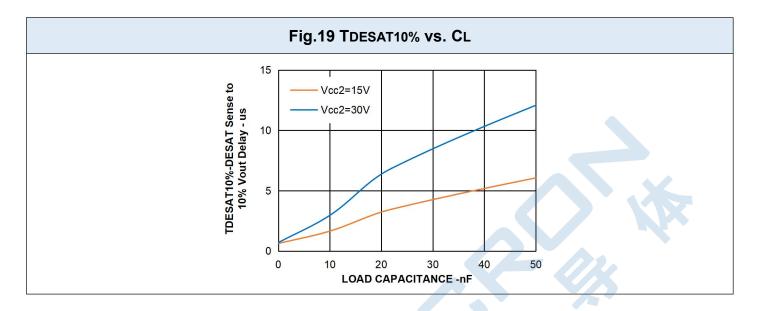




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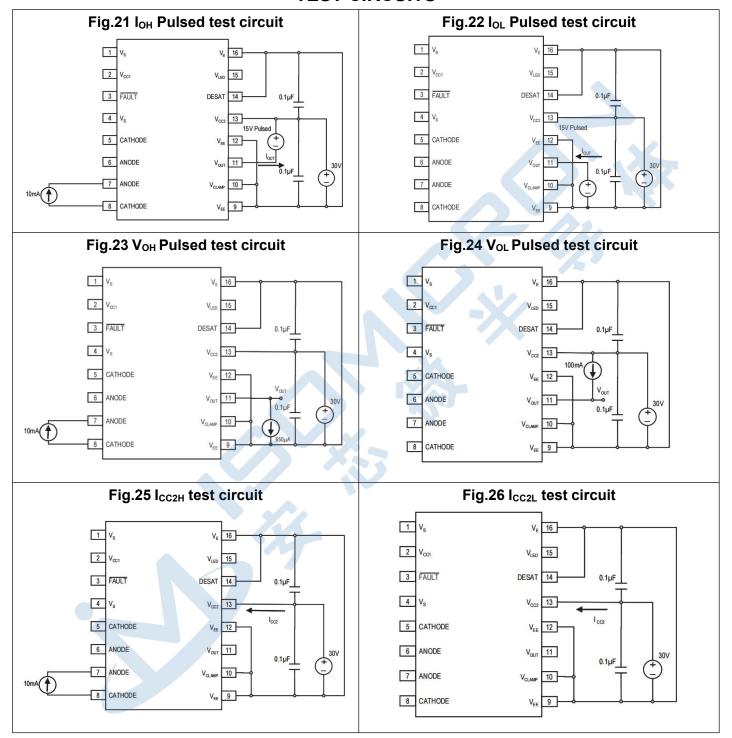


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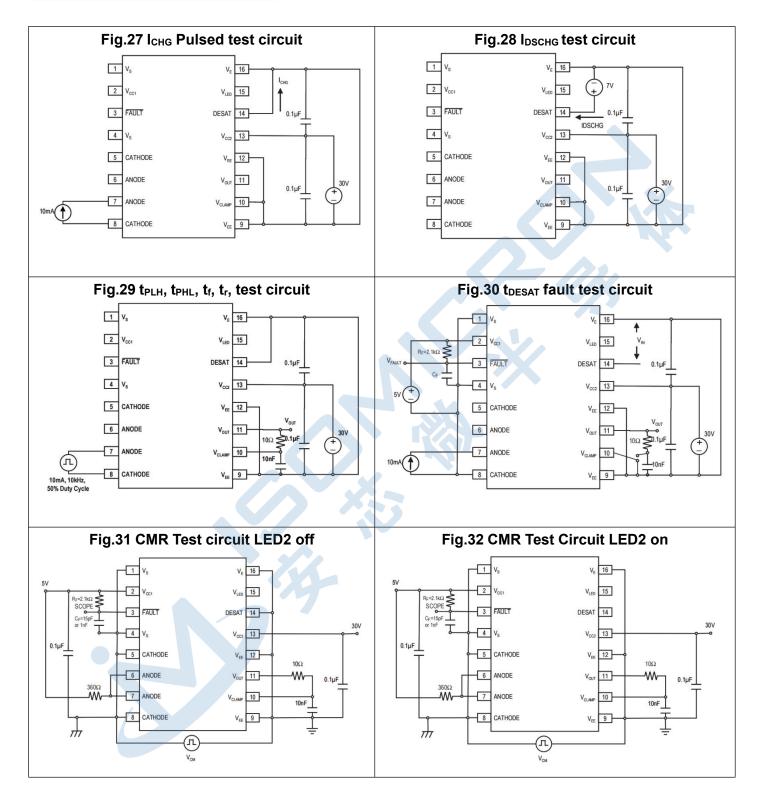
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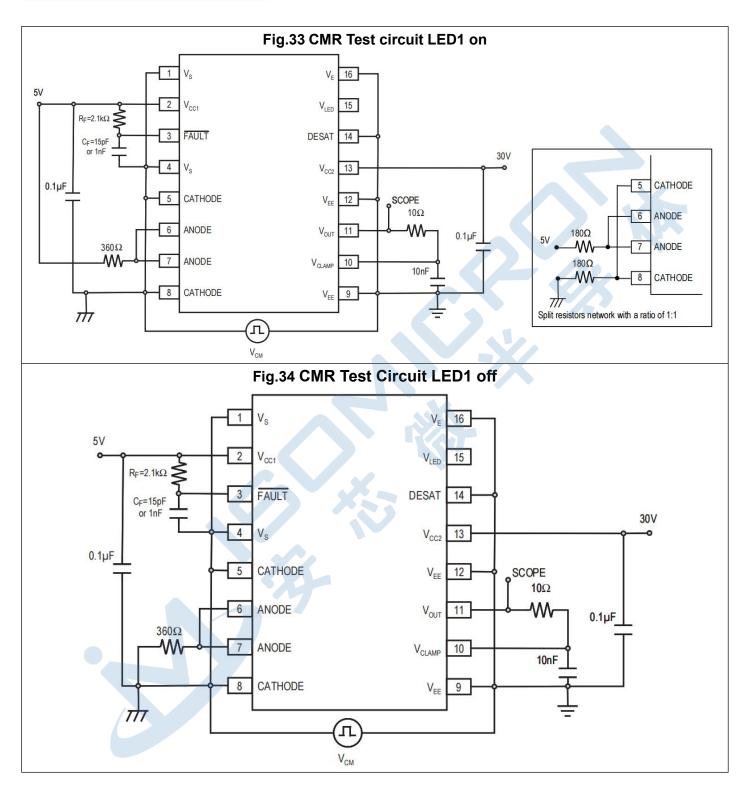
### **TEST CIRCUITS**













# **Application Information Product Overview Description**

The ICPL-332J is a highly integrated power control device that incorporates all the necessary components for a complete, isolated IGBT / MOSFET gate drive circuit with fault protection and feedback into one SO-16 package. Active Miller clamp function eliminates the need of negative gate drive in most application and allows the use of simple bootstrap supply for high side driver. An optically isolated power output stage drives IGBTs with power ratings of up to 150A and 1200V. A high speed internal optical link minimizes the propagation delays between the microcontroller and the IGBT while allowing the two systems to operate at very large common mode voltage differences that are common in industrial motor drives and other power switching applications. An output IC provides local protection for the IGBT to prevent damage during over current, and a second optical link provides a fully isolated fault status feedback signal for the microcontroller. A built in "watchdog" circuit, UVLO monitors the power stage supply voltage to prevent IGBT caused by insufficient gate drive voltages. This integrated IGBT gate driver is designed to increase the performance and reliability of a motor drive without the cost, size, and complexity of a discrete design.

Two light emitting diodes and two integrated circuits housed in the same SO-16 package provide the input control circuitry, the output power stage, and two optical channels. The output Detector IC is designed manufactured on a high voltage BiCMOS/Power DMOS process. The forward optical signal path, as indicated by LED1, transmits the gate control signal. The return optical signal path, as indicated by LED2, transmits the fault status feedback signal.

Under normal operation, the LED1 directly controls the IGBT gate through the isolated output detector IC, and LED2 remains off. When an IGBT fault is detected, the output detector IC immediately begins a "soft" shutdown sequence, reducing the IGBT current to zero in a controlled manner to avoid potential IGBT damage from inductive over voltages. Simultaneously, this fault status is transmitted back to the input via LED2, where the fault latch disables the gate control input and the active low fault output alerts the microcontroller.

During power-up, the Under Voltage Lockout (UVLO) feature prevents the application of insufficient gate voltage to the IGBT, by forcing the ICPL-332J's output low. Once the output is in the high state, the DESAT (VCE) detection feature of the ICPL-332J provides IGBT protection. Thus, UVLO and DESAT work in conjunction to provide constant IGBT protection.

ICPL-332J

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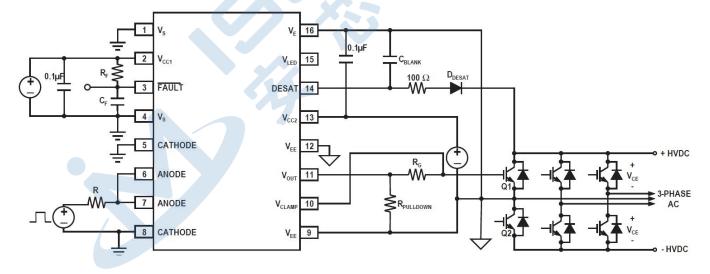


# **Recommended Application Circuit**

The ICPL-332J has an LED input gate control, and an open collector fault output suitable for wired 'OR' applications. The recommended application circuit shown in Figure 35 illustrates a typical gate drive implementation using the ICPL-332J. The following describes about driving IGBT. However, it is also applicable to MOSFET. Depending upon the MOSFET or IGBT gate threshold requirements, designers may want to adjust the  $V_{CC}$  supply voltage (Recommended  $V_{CC}$  = 17.5V for IGBT and 12.5V for MOSFET).

The two supply bypass capacitors (0.1  $\mu$ F) provide the large transient currents necessary during a switching transition. Because of the transient nature of the charging currents, a low current (5mA) power supply suffices. The desaturation diode DDESAT 600V/1200V fast recovery type, trr below 75ns (e.g. ERA34-10) and capacitor CBLANK are necessary external components for the fault detection circuitry. The gate resistor RG serves to limit gate charge current and controls the IGBT collector voltage rise and fall times. The open collector fault output has a passive pull-up resistor RF (2.1 k $\Omega$ ) and a 1000 pF filtering capacitor, CF. A 47k $\Omega$  pull down resistor RPULL-DOWN on V<sub>OUT</sub> provides a predictable high level output voltage (V<sub>OH</sub>). In this application, the IGBT gate driver will shut down when a fault is detected and fault reset by next cycle of IGBT turn on. Application notes are mentioned at the end of this datasheet.

Fig.35 Recommended application circuit (Single Supply) with desaturation detection and active Miller Clamp



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# **Description of Operation-Normal Operation**

During normal operation, V<sub>OUT</sub> of the ICPL-332J is controlled by input LED current IF (pins 5, 6, 7 and 8), with the IGBT collector-to-emitter voltage being monitored through DESAT. The FAULT output is high. See Figure 36.

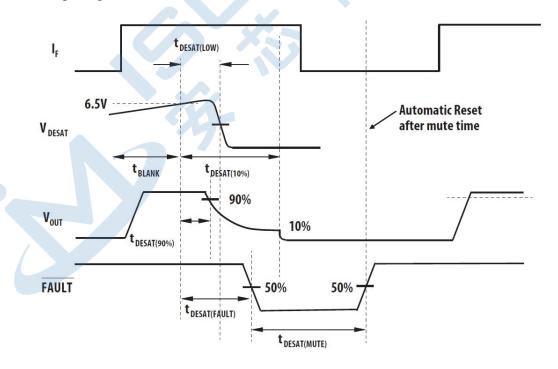
### **Fault Condition**

The DESAT pin monitors the IGBT Vce voltage. When the voltage on the DESAT pin exceeds 6.5 V while the IGBT is on,  $V_{OUT}$  is slowly brought low in order to "softly" turn-off the IGBT and prevent large di/dt induced voltages. Also activated is an internal feedback channel which brings the FAULT output low for the purpose of notifying the micro-controller of the fault condition.

#### **Fault Reset**

Once fault is detected, the output will be muted for 5µs (minimum). All input LED signals will be ignored during the fault period to allow the driver to completely soft shut-down the IGBT. The fault mechanism can be reset by the next LED turn-on after the 5µs (minimum)mute time. See Figure 36.





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# **Output Control**

The outputs ( $V_{OUT}$  and FAULT) of the ICPL-332J are controlled by the combination of  $I_F$ , UVLO and a detected IGBT Desat condition. Once UVLO is not active ( $V_{CC2}$  -  $V_E$  >  $V_{UVLO}$ ),  $V_{OUT}$  is allowed to go high, and the DESAT (pin 14) detection feature of the ICPL-332J will be the primary source of IGBT protection. Once  $V_{CC2}$  is increased from 0V to above  $V_{UVLO+}$ , DESAT will remain functional until  $V_{CC2}$  is decreased below  $V_{UVLO-}$ . Thus, the DESAT detection and UVLO features of the ICPL-332J work in conjunction to ensure constant IGBT protection.

I <sub>F</sub>	UVLO(V <sub>CC2</sub> -V <sub>E</sub> )	DESAT Function	FAULT Output	VOUT
ON	Active	Not Active	High	Low
ON	Not Active	Active (with DESAT fault)	Low (FAULT)	Low
ON	Not Active	Not Active (no DESAT fault)	High (or no fault)	High
OFF	Active	Not Active	High	Low
OFF	Not Active	Not Active	High	Low



# **Desaturation Detection and High Current Protection**

The ICPL-332J satisfies these criteria by combining a high speed, high output current driver, high voltage optical isolation between the input and output, local IGBT desaturation detection and shut down, and an optically isolated fault status feedback signal into a single 16-pin surface mount package.

The fault detection method, which is adopted in the ICPL-332J is to monitor the saturation (collector) voltage of the IGBT and to trigger a local fault shutdown sequence if the collector voltage exceeds a predetermined threshold. A small gate discharge device slowly reduces the high short circuit IGBT current to prevent damaging voltage spikes. Before the dissipated energy can reach destructive levels, the IGBT is shut off. During the off state of the IGBT, the fault detect circuitry is simply disabled to prevent false 'fault' signals.

The alternative protection scheme of measuring IGBT current to prevent desaturation is effective if the short circuit capability of the power device is known, but this method will fail if the gate drive voltage decreases enough to only partially turn on the IGBT. By directly measuring the collector voltage, the ICPL-332J limits the power dissipation in the IGBT even with insufficient gate drive voltage. Another more subtle advantage of the desaturation detection method is that power dissipation in the IGBT is monitored, while the current sense method relies on a preset current threshold to predict the safe limit of operation. Therefore, an overly conservative over current threshold is not needed to protect the IGBT.

# **Slow IGBT Gate Discharge during Fault Condition**

When a desaturation fault is detected, a weak pull-down device in the ICPL-332J output drive stage will turn on to 'softly' turn off the IGBT. This device slowly discharges the IGBT gate to prevent fast changes in drain current that could cause damaging voltage spikes due to lead and wire inductance. During the slow turn off, the large output pull-down device remains off until the output voltage falls below  $V_{\text{EE}}$  + 2 Volts, at which time the large pull down device clamps the IGBT gate to  $V_{\text{EE}}$ .

# **DESAT Fault Detection Blanking Time**

The DESAT fault detection circuitry must remain disabled for a short time period following the turn-on of the IGBT to allow the collector voltage to fall below the DESAT threshold. This time period, called the DESAT blanking time is controlled by the internal DESAT charge current, the DESAT voltage threshold, and the external DESAT capacitor.

The nominal blanking time is calculated in terms of external capacitance ( $C_{BLANK}$ ), FAULT threshold voltage ( $V_{DESAT}$ ), and DESAT charge current ( $I_{CHG}$ ) as  $I_{BLANK} = C_{BLANK} \times V_{DESAT} / I_{CHG}$ . The nominal blanking time with the recommended 100pF capacitor is 100pF \* 6.5V / 240 $\mu$ A = 2.7 $\mu$ sec. The capacitance value can be scaled slightly to adjust the blanking time, though a value smaller than 100 pF is not recommended. This nominal blanking time represents the longest time it will take for the ICPL-332J to respond to a DESAT fault condition. If the IGBT is turned on while the collector and emitter are shorted to the supply rails (switching into a short), the soft shut-down sequence will begin after approximately 3  $\mu$ sec. If the IGBT collector and emitter are shorted to the supply rails after the IGBT is already on, the response time will be much quicker due to the parasitic parallel capacitance of the DESAT diode. The recommended 100pF capacitor should provide adequate blanking as well as fault response times for most applications.

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# **Under Voltage Lockout**

The ICPL-332J Under Voltage Lockout (UVLO) feature is designed to prevent the application of insufficient gate voltage to the IGBT by forcing the ICPL-332J output low during power-up. IGBTs typically require gate voltages of 15V to achieve their rated  $V_{\text{CE}(ON)}$  voltage. At gate voltages below 13V typically, the  $V_{\text{CE}(ON)}$  voltage increases dramatically, especially at higher currents. At very low gate voltages (below 10V), the IGBT may operate in the linear region and quickly overheat. The UVLO function causes the output to be clamped whenever insufficient operating supply ( $V_{\text{CC2}}$ ) is applied. Once  $V_{\text{CC2}}$  exceeds  $V_{\text{UVLO+}}$  (the positive-going UVLO threshold), the UVLO clamp is released to allow the device output to turn on in response to input signals. As  $V_{\text{CC2}}$  is increased from 0 V (at some level below  $V_{\text{UVLO+}}$ ), first the DESAT protection circuitry becomes active. As  $V_{\text{CC2}}$  is further increased (above  $V_{\text{UVLO+}}$ ), the UVLO clamp is released. Before the time the UVLO clamp is released, the DESAT protection is already active. Therefore, the UVLO and DESAT Fault detection feature work together to provide seamless protection regardless of supply voltage ( $V_{\text{CC2}}$ ).

# **Active Miller Clamp**

A Miller clamp allows the control of the Miller current during a high  $d_V/dt$  situation and can eliminate the use of a negative supply voltage in most of the applications. During turn-off, the gate voltage is monitored and the clamp output is activated when gate voltage goes below 2V (relative to  $V_{EE}$ ). The clamp voltage is  $V_{OL}+2.5V$  typ for a Miller current up to 1100mA. The clamp is disabled when the LED input is triggered again.

# **Other Recommended Components**

The application circuit in Figure 33 includes an output pull-down resistor, a DESAT pin protection resistor, a FAULT pin capacitor, and a FAULT pin pullup resistor and Active Miller Clamp connection.

# **Output Pull-Down Resistor**

During the output high transition, the output voltage rapidly rises to within 3 diode drops of  $V_{CC2}$ . If the output current then drops to zero due to a capacitive load, the output voltage will slowly rise from roughly  $V_{CC2}$ -3( $V_{BE}$ ) to  $V_{CC2}$  within a period of several microseconds. To limit the output voltage to  $V_{CC2}$ -3( $V_{BE}$ ), a pull-down resistor, RPULL-DOWN between the output and  $V_{EE}$  is recommended to sink a static current of several 650  $\mu$ A while the output is high. Pull-down resistor values are dependent on the amount of positive supply and can be adjusted according to the formula, Rpull-down = [ $V_{CC2}$ -3 \* ( $V_{BE}$ )] / 650  $\mu$ A.

### **DESAT Pin Protection Resistor**

The freewheeling of flyback diodes connected across the IGBTs can have large instantaneous forward voltage transients which greatly exceed the nominal forward voltage of the diode. This may result in a large negative voltage spike on the DESAT pin which will draw substantial current out of the driver if protection is not used. To limit this current to levels that will not damage the driver IC, a 100 ohm resistor should be inserted in series with the DESAT diode. The added resistance will not alter the DESAT threshold or the DESAT blanking time.

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Fig.37 Output pull-down resistor.

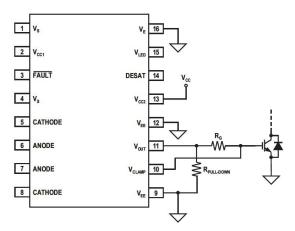
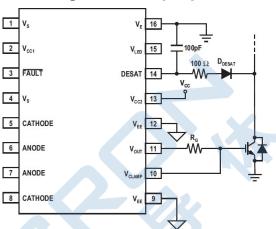


Fig.38 DESAT pin protection



# Capacitor on FAULT Pin for High CMR

Rapid common mode transients can affect the fault pin voltage while the fault output is in the high state. A 1000 pF capacitor should be connected between the fault pin and ground to achieve adequate CMOS noise margins at the specified CMR value of 50 kV/µs.

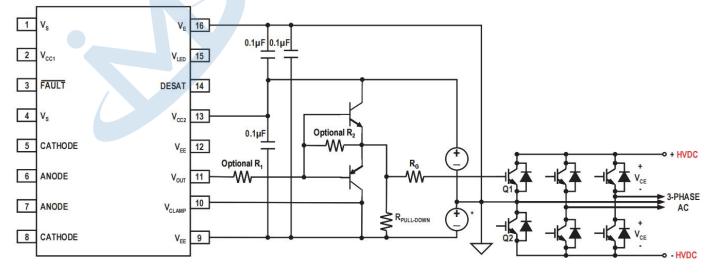
# **Pull-up Resistor on FAULT Pin**

The FAULT pin is an open collector output and therefore requires a pull-up resistor to provide a high-level signal. Also the FAULT output can be wire 'OR'ed together with other types of protection (e.g. over-temperature, over-voltage, over-current) to alert the microcontroller.

# Other Possible Application Circuit (Output Stage)

Fig.39 IGBT drive with negative gate drive, external booster and desaturation detection ( $V_{\text{CLAMP}}$  should be connected to  $V_{\text{EE}}$  when it is not used)  $V_{\text{CLAMP}}$  is used as secondary gate discharge path.

\* indicates component required for negative gate drive topology

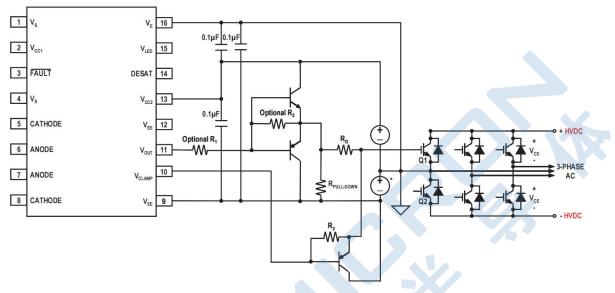


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Fig.40 Large IGBT drive with negative gate drive, external booster. V<sub>CLAMP</sub> control secondary discharge path for higher power application.



#### Thermal Model

The ICPL-332J is designed to dissipate the majority of the heat through pins 1, 4, 5 & 8 for the input IC and pins 9 &12 for the output IC. (There are two VEE pins on the output side, pins 9 and 12, for this purpose.) Heat flow through other pins or through the package directly into ambient are considered negligible and not modeled here. In order to achieve the power dissipation specified in the absolute maximum specification, it is imperative that pins 5, 9, and 12 have ground planes connected to them. As long as the maximum power specification is not exceeded, the only other limitation to the amount of power one can dissipate is the absolute maximum junction temperature specification of 125°C. The junction temperatures can be calculated with the following equations:

$$T_{ji}$$
 = Pi ( $\theta$ i5 +  $\theta$ 5A) +  $T_a$ 

$$T_{jo} = Po (\theta o 9, 12 + \theta 9, 12A) + T_a$$

Where Pi = power into input IC and Po = power into output IC. Since  $\theta$ 5A and  $\theta$ 9,12A are dependent on PCB layout and airflow, their exact number may not be available. Therefore, a more accurate method of calculating the junction temperature is with the following equations:

$$T_{ii} = Pi\theta i5 + TP5$$

$$T_{j_0} = P_0\theta_09,12 + T_{p_0}\theta_09,12$$

These equations, however, require that the pin 5 and pins 9, 12 temperatures be measured with a thermal couple on the pin at the ICPL-332J package edge.

If the calculated junction temperatures for the thermal model in Figure 38 is higher than 125°C, the pin temperature for pins 9 and 12 should be measured (at the package edge) under worst case operating environment for a more accurate estimate of the junction temperatures.

 $T_{ii}$  = junction temperature of input side IC

 $T_{io}$  = junction temperature of output side IC TP5 = pin 5 temperature at package edge

TP9, 2 = pin 9 and 12 temperature at package edge

 $\theta$ I5 = input side IC to pin 5 thermal resistance

 $\theta$ 09,12 = output side IC to pin 9 and 12 thermal resistance

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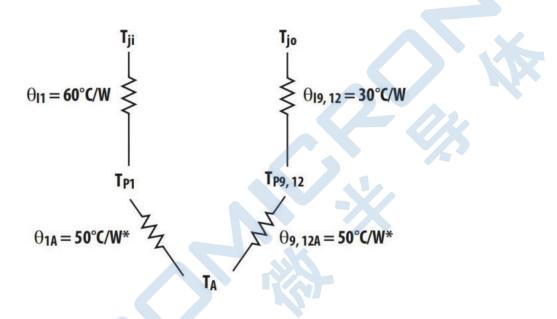
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 $\theta$ 5A = pin 5 to ambient thermal resistance  $\theta$ 9,12A = pin 9 and 12 to ambient thermal resistance

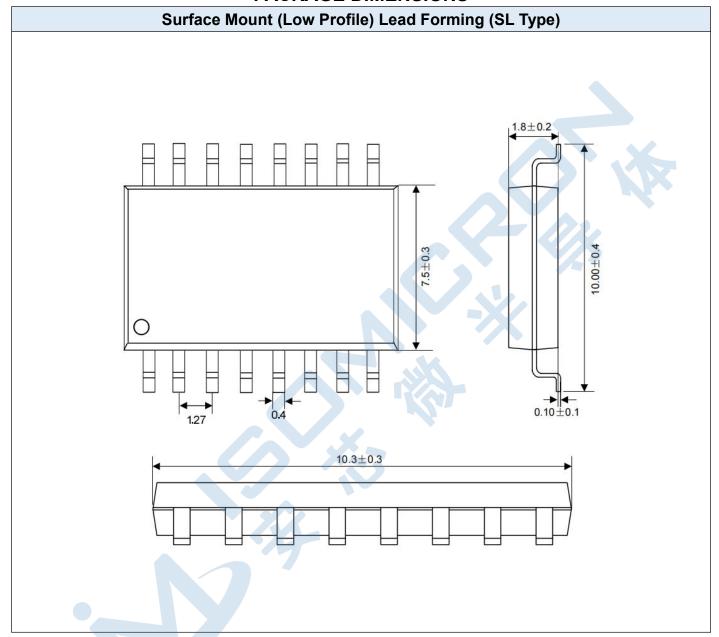
\*The  $\theta$ 5A and  $\theta$ 9,12A values shown here are for PCB layouts with reasonable air flow. This value may increase or decrease by a factor of 2 depending on PCB layout and/or airflow.

Fig.38 ICPL-332J Thermal Model





# **PACKAGE DIMENSIONS**



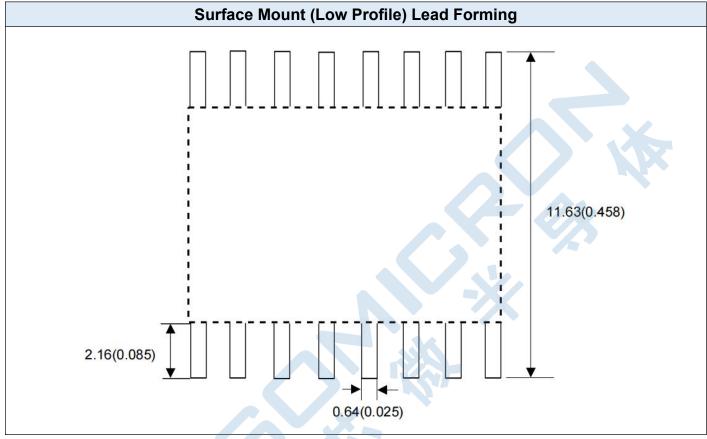
Dimensions in mm unless otherwise stated

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# **RECOMMENDED SOLDER MASK**

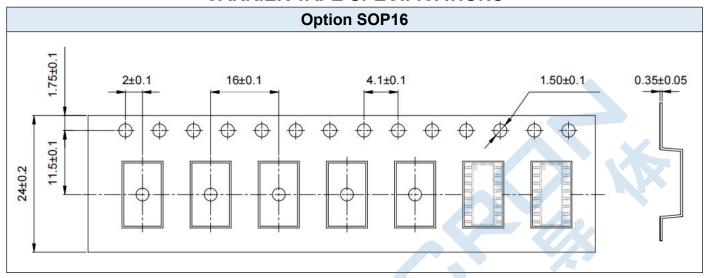


Dimensions in mm unless otherwise stated





# **CARRIER TAPE SPECIFICATIONS**



Dimensions in mm unless otherwise stated

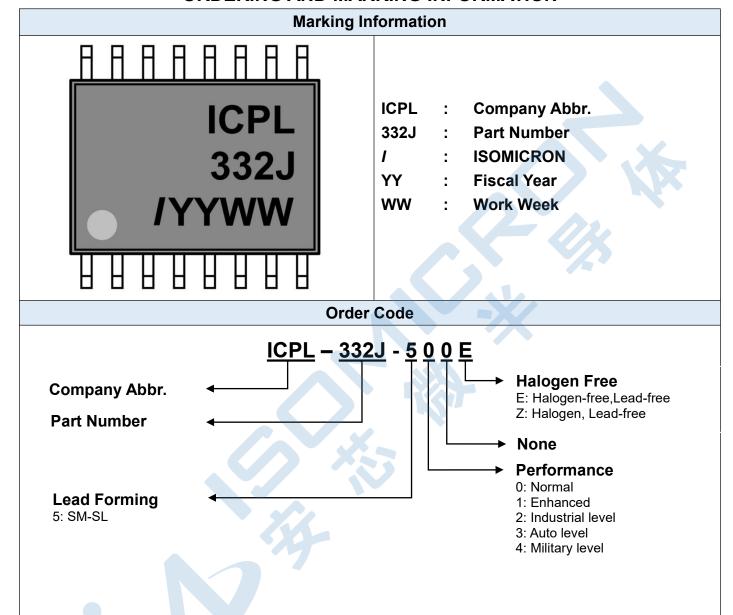


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### ORDERING AND MARKING INFORMATION



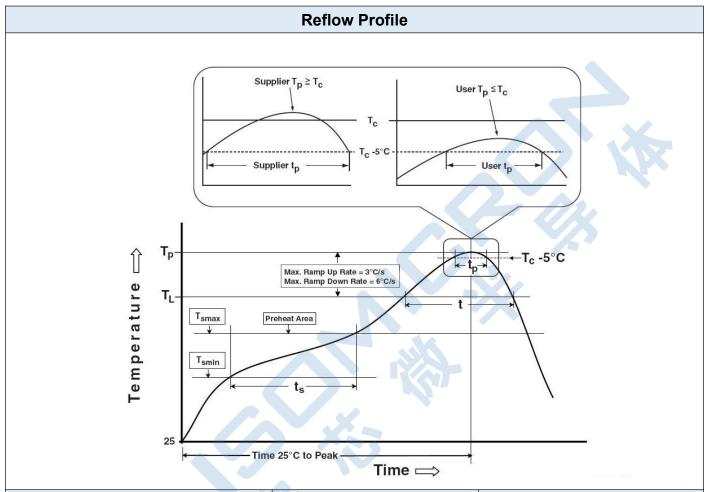
Packing Quantity						
Option		Quantity	Quantity	Quantity – Outer box		
SM-SL 1000 Units/Re		1000 Units/Reel	2	5 Inner box/Outer box = 10K Units		

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# **REFLOW INFORMATION**



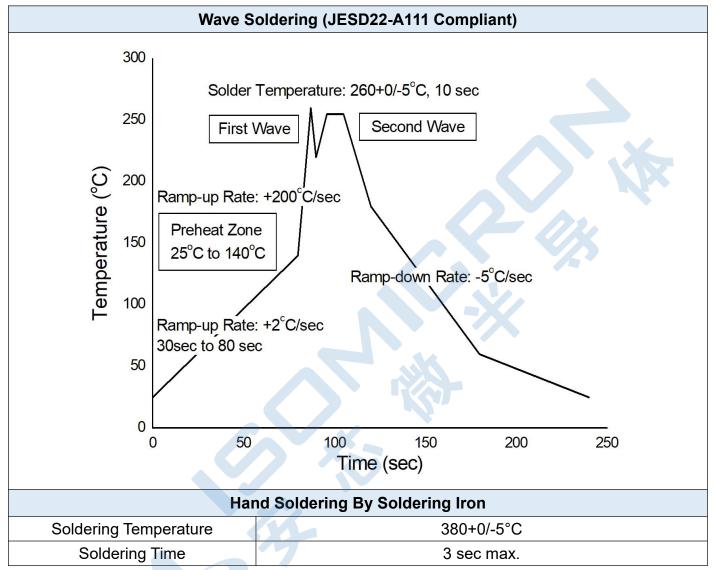
Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	100	150°C
Temperature Max. (Tsmax)	150	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds	60-120 seconds
Ramp-up Rate (tL to tP)	3°C/second max.	3°C/second max.
Liquidous Temperature (TL)	183°C	217°C
Time (tL) Maintained Above (TL)	60 – 150 seconds	60 – 150 seconds
Peak Body Package Temperature	235°C +0°C / -5°C	260°C +0°C / -5°C
Time (tP) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (TP to TL)	6°C/second max	6°C/second max
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

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### TEMPERATURE PROFILE OF SOLDERING



- One time soldering is recommended for all soldering method.
- Do not solder more than three times for IR reflow soldering.

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  customer application by the customer's technical experts. Product specifications do not expand or
  otherwise modify ISOMICRON's terms and conditions of purchase, including but not limited to the
  warranty expressed therein.
- Discoloration might be occurred on the package surface after soldering, reflow or long-time use. It neither impacts the performance nor reliability.

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